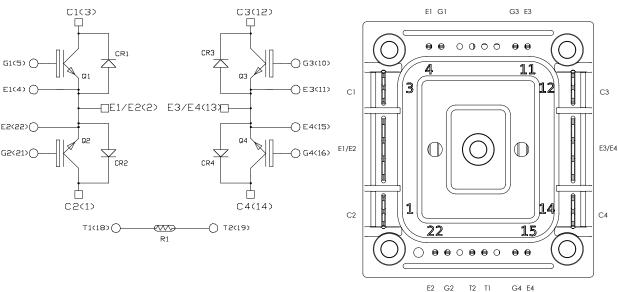
Double Dual Common Emitter High-Speed IGBT4 Power Module

Product Overview

The MSCGLQ75DDU120CTBL3NG device is a 1200 V/75 A double dual common emitter high-speed IGBT4 power module.





All ratings at T_J = 25 °C, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are the key features of MSCGLQ75DDU120CTBL3NG device:

- · High speed IGBT4
 - Low voltage drop
 - Low leakage current
 - Low switching losses
- · SiC Schottky Diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature independent switching behavior
 - Positive temperature coefficient on V_F
- · Ultra-low weight and profile
- Kelvin emitter for easy drive
- Si₃N₄ substrate with thick copper for improved thermal performance
- Internal thermistor for temperature monitoring
- Extended temperature range

Benefits

The following are the benefits of MSCGLQ75DDU120CTBL3NG device:

- High efficiency converter
- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction-to-heatsink thermal resistance
- Low profile
- RoHS compliant
- Solderable terminals both for power and signal for easy PCB mounting
- Very integrated power conversion system

Application

The following are the applications of MSCGLQ75DDU120CTBL3NG device:

- · High reliability power systems
- AC switches

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1. Electrical Specifications

This section provides the electrical specifications of MSCGLQ75DDU120CTBL3NG device.

1.1 IGBT4 Characteristics (Per IGBT)

The following table lists the absolute maximum ratings of MSCGLQ75DDU120CTBL3NG device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter	Parameter I		Unit
V _{CES}	Collector-Emitter voltage	or-Emitter voltage		V
I _C	C Continuous collector current T _H = 2		160	Α
		T _H = 80 °C	75	
I _{CM}	Pulsed collector current	T _H = 25 °C	250	
V _{GE}	Gate-Emitter voltage	Sate-Emitter voltage		V
P _D	Power dissipation		470	W

The following table lists the electrical characteristics of MSCGLQ75DDU120CTBL3NG device.

Table 1-2. Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I _{CES}	Zero gate voltage collector current	V _{GE} = 0 V V _{CE} = 1200 V		_	_	50	μΑ
V _{CE(sat)}	Collector emitter	V _{GE} = 15 V	T _J = 25 °C	1.7	2.05	2.4	V
	saturation voltage	I _C = 75 A	T _J = 150 °C	_	2.6	_	
$V_{GE(th)}$	Gate threshold voltage	$V_{GE} = V_{CE}$ $I_C = 2.6 \text{ mA}$		5.3	5.8	6.3	V
I _{GES}	Gate-Emitter leakage current	V _{GE} = 20 V V _{CE} = 0 V		_	_	150	nA

Electrical Specifications

The following table lists the dynamic characteristics of MSCGLQ75DDU120CTBL3NG device.

Table 1-3. Dynamic Characteristics

Symbol	Characteristic	Test Condition	าร		Min	Тур	Max	Unit
C _{ies}	Input capacitance	V _{GE} = 0 V	V _{GE} = 0 V			4400	_	pF
C _{oes}	Output capacitance	V _{CE} = 25 V			_	250	_	
C _{res}	Reverse transfer capacitance	f = 1 MHz			_	235	_	
Q _g	Gate charge	$V_{GE} = 15 \text{ V}$ $V_{CE} = 960 \text{ V}$ $I_{C} = 75 \text{ A}$	V _{CE} = 960 V		_	325	_	nC
T _{d(on)}	Turn-on delay time	V _{GE} = ±15 V		T _J = 150 °C	_	30	_	ns
T _r	Rise time	V _{Bus} = 600 V	' _{Bus} = 600 V	_	49	_		
T _{d(off)}	Turn-off delay time	I _C = 75 A			_	366	_	
T _f	Fall time	$R_G = 6.4 \Omega$				48	_	
E _{on}	Turn-on switching energy	V _{GE} = ±15 V V _{Bus} = 600 V		T _J = 150 °C	_	3.84	_	mJ
E _{off}	Turn-off switching energy	$I_{C} = 75 \text{ A}$ $R_{G} = 6.4 \Omega$		T _J = 150 °C	_	3.84	_	
R _G	Integrated gate resist	or			_	10	_	Ω
I _{SC}	Short circuit data	$V_{GE} \le 15 \text{ V}$ $V_{Bus} = 900 \text{ V}$ $t_p \le 10 \mu \text{s}$		T _j = 150 °C	_	260		A
R _{thJH}	Junction-to-heatsink resistance	thermal	$\lambda_{\text{paste}} = 3.4 \text{ W}$	/mK		0.318		°C/W

1.2 SiC Diode Ratings and Characteristics (Per SiC Diode)

The following table lists the SiC diode ratings and characteristics of MSCGLQ75DDU120CTBL3NG device.

Table 1-4. SiC Diode Ratings and Characteristics

Symbol	Characteristic	Test Condition	ons		Min	Тур	Max	Unit
V_{RRM}	Peak repetitive reverse	voltage			<u> </u>	_	1200	V
I _{RM}	Reverse leakage	age V _R = 1200 V	T _J = 25 °C	_	10	200	μA	
	current				_	250	_	
I _F	DC forward current			T _H = 100 °C	_	50	_	А
V _F	Diode forward voltage I _F = 50 A			T _J = 25 °C	_	1.5	1.8	V
		1		T _J = 175 °C	_	2.1	_	
Q _C	Total capacitive charge	V _R = 600 V			_	224	_	nC
С	Total capacitance	f = 1 MHz V _R = 400 V		_	246	_	pF	
		f = 1 MHz V _R = 800 V		_	182	_		
R _{thJH}	Junction-to-heatsink the resistance	rmal	$\lambda_{\text{paste}} = 3.4 \ \text{V}$	N/mK	_	0.635	_	°C/W

1.3 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCGLQ75DDU120CTBL3NG device.

Table 1-5. Thermal and Package Characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
V _{ISOL}	RMS isolation voltage, any terminal to case t = 1 min, 50 Hz/60 Hz			2500	_	_	V
T _J	Operating junction temperature range			- 55	_	175	°C
T _{JOP}	Recommended junction temperature under switching conditions			- 55	_	T _{Jmax} –25	
T _{STG}	Storage case temperature			– 55	_	125	
T _C	Operating case temperature			- 55	_	125	
Torque	Mounting torque	que To heatsink M3			_	0.9	N.m
Wt	Package weight			_	32.5	_	g

The following table lists the temperature sensor NTC of the MSCGLQ75DDU120CTBL3NG device.

Table 1-6. Temperature Sensor NTC

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance at 25 °C		_	50	_	kΩ
$\Delta R_{25}/R_{25}$	25		_	5	_	%
B _{25/85}	T ₂₅ = 298.15 K		_	3952	_	K
ΔΒ/Β	_	T _C = 100 °C	_	4	_	%

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

Note: See APT0406—Using NTC Temperature Sensor Integrated into Power Module for more information.

1.4 Typical IGBT4 Performance Curve (Per IGBT)

This section shows the typical IGBT4 performance curves of MSCGLQ75DDU120CTBL3NG device.

Figure 1-1. Junction-to-Heatsink Thermal Impedance

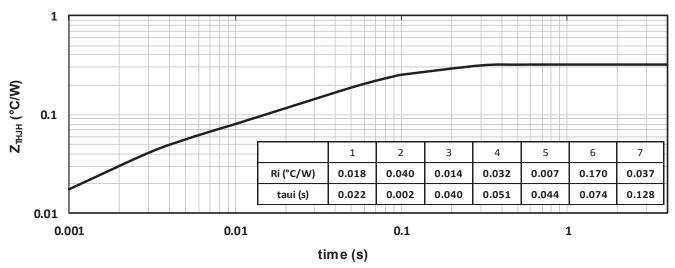


Figure 1-2. Output Characteristics ($V_{GE} = 15 \text{ V}$)

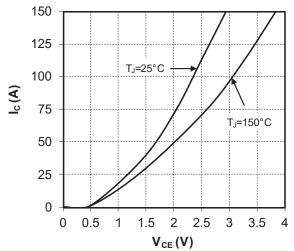


Figure 1-3. Output Characteristics

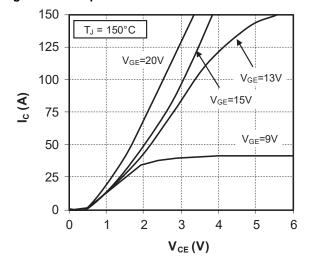


Figure 1-4. Transfer Characteristics

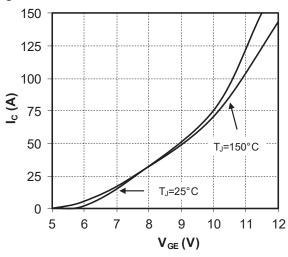


Figure 1-5. Energy Losses vs. Collector Current

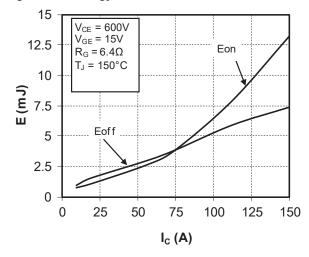


Figure 1-6. Switching Energy Losses vs. Gate Resistance

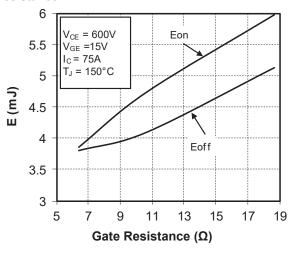
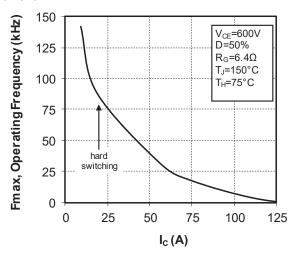


Figure 1-7. Operating Frequency vs. Collector Current



1.5 Typical SiC Diode Performance Curves (Per SiC Diode)

This section shows the typical SiC diode performance curves of MSCGLQ75DDU120CTBL3NG device.

Figure 1-8. Junction-to-Heatsink Thermal Impedance

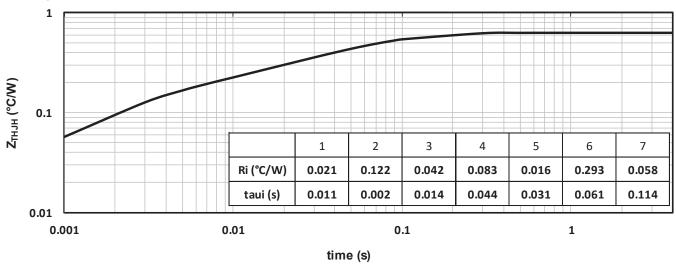


Figure 1-9. Forward Characteristics

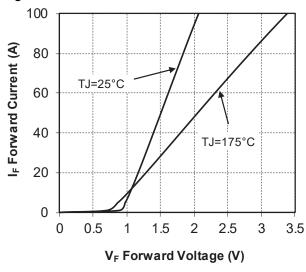
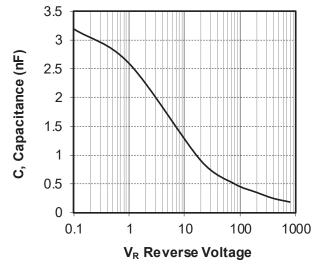


Figure 1-10. Capacitance vs. Reverse Voltage



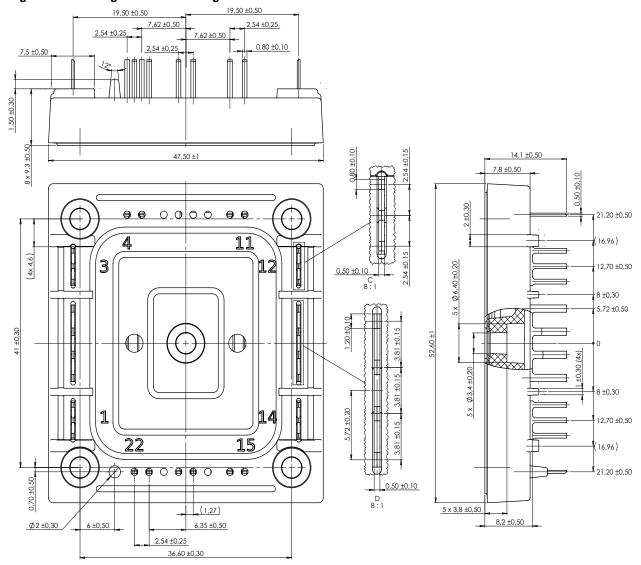
2. Package Specifications

The following section shows the package specification of MSCGLQ75DDU120CTBL3NG device.

2.1 Package Outline

The following figure shows the package outline drawing of MSCGLQ75DDU120CTBL3NG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



Revision History

3. Revision History

Revision	Date	Description
Α	07/2021	Initial revision

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